

OX-204 at 10 MHz

Ultra Low Phase Noise Oven Controlled Crystal Oscillator



The OX-204 is an Ultra Low Phase Noise Ovenized Crystal Oscillator with a noise floor as low as -175 dBc/Hz. Designed for applications that demand extremely low noise sources, including the reference oscillator for a phase-locked loop in the microwave spectrum. Custom frequencies available upon request.

Features

- -140 dBc/ Hz at 10 Hz offset
- · -175 dBc/Hz at 10 kHz offset
- 10 MHZ standard, other frequencies available

Applications

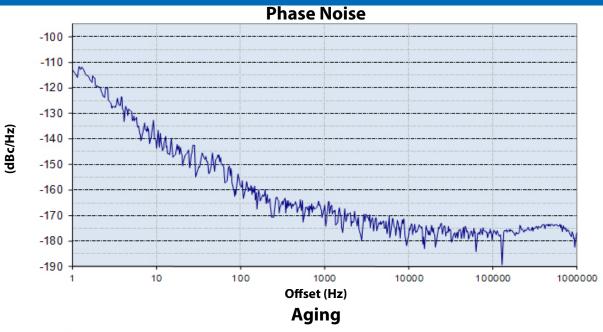
- Military Radar
- Instrumentation and Test Equipment
- Synthesizers
- Military Communication Equipment
- · DRO reference
- Satellite Communications

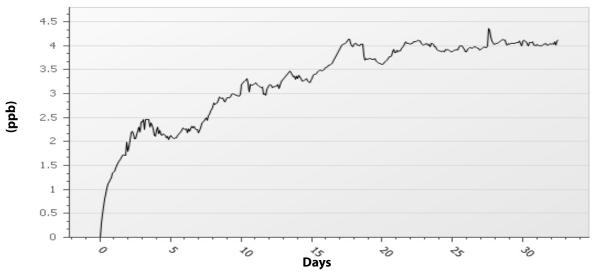
Performance Specifications

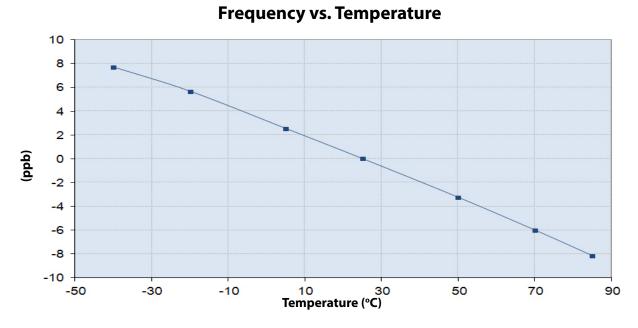
Phase Noise Ordering Codes at 10 MHz							
Frequency Offset (Hz)	А	В	C (12V only)	D (12V only)	E (5V only)	Unit	Condition
1	-95	-100	-105	-110	-105	dBc/Hz	Maximum values All EFC settings
10	-125	-130	-135	-140	-135		
100	-150	-155	-157	-157	-157		
1000	-160	-165	-167	-165	-167		
10,000	-170	-170	-175	-170	-172		
100,000	-170	-170	-175	-170	-173		
Frequency Stabilities at 10 MHz							

Frequency Stabilities at 10 MHz							
Parameter	Min	Typical	Max	Unit	Condition		
vs. operating temperature range	-10		+10	ppb	-20 to +70°C (referenced to +25°C)		
	-20		+20	ppb	-40 to +85°C (referenced to +25°C)		
vs. Initial Tolerance	-100		+100	ppb	at time of shipment and 5V efc		
Allan Deviation			5	E-12	0.1 to 1 second tau		
vs. supply voltage change	-2		+2	ppb	±5% change		
vs. load change	-2		+2	ppb	5% change in load		
vs. aging / 1 day	-0.5		+0.5	ppb	after 7 days of operation		
vs. aging / 1 st year	-100		+100	ppb	after 7 days of operation		
vs. aging / year	-30		+30	ppb	after first year of operation		
Warm up time			5	minutes	to ±10 ppb of 2-hour frequency @+25℃		

Product Performance Data





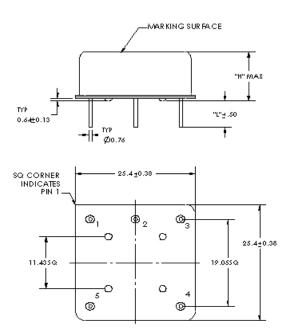


Performance Specifications

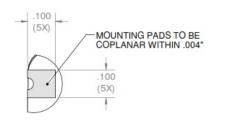
Supply Voltage (Vs)						
Parameter	Min	Typical	Max	Unit	Condition	
	11.4	12.0	12.6	VDC		
Supply Voltage	4.75	5	5.25	VDC		
Dawer Consumentian			4.0	Watts	during warm-up	
Power Consumption			1.8	Watts	steady state @ +25°C	
Reference Voltage		10		VDC	12 V version	
nererence voltage		4.35		VDC	5 V version	
	Y	F	RF Output			
Signal		Sine	wave			
Load		50		Ohms		
Output Power	+7.0		+13.0	dBm	50 Ohm load @ Vs=12V	
	+4.0		+7.0	dBm	50 Ohm load @ Vs=5V	
Harmonics			-30	dBc	50 Ohm load	
Spurious			-80	dBc	50 Ohm load	
		Freque	ncy Tuning	(EFC)		
Tuning Range	±400		±800	ppb	enough for aging over 15 year lifetime	
Linearity			15	%		
Tuning Slope	Positive					
Control Voltage Range	0		10	VDC	Vs=12V	
	0		4.35		Vs=5V	
Input Impedance		100		kOhm		
Modulation Bandwidth	150			Hz		
		Additio	nal Param	eters		
g-sensitivity			1.5	ppb/g		
Weight			20	grams		
		Absolute	Maximum	Ratings		
Parameter	Min	Typical	Max	Unit	Condition	
Supply Voltage (Vs)			15	٧	12V version	
			7	V	5V version	
Output Load			25	Ohms		
Operable Temperature Range	-55		+95	°C	Device will not sustain damage when operated at temperatures between the operating range and the operable range, but will not be specification compliant	
	Envi	ronmental a	and Produc	t Classification	n	
Shock (Endurance)	MIL-STD-202,	Method 213	, Condition J	, 30g 11 ms		
Sine Vibration (Endurance)	MIL-STD-202, Method 201 and 204, Condition A, except 5g to 500 Hz, 1 sweep each axis					
Random Vibration (Endurance)	MIL-STD-202, Method 214, Condition I-D					
Humidity	MIL-STD-202, Method 103, Condition B, 100% rh					
Seal	MIL-STD-202, Method 112, Condition D					
Altitude	MIL-STD-202, Method 105, sea level to space					
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition A,B,C					
Terminal Strength	MIL-STD-202, Method 11, Condition C (5 bends at 45°, 2 lbs)					
Moisture Sensitive Level	1					
Moistule Selisitive Level	1					
RoHS	6 (fully comp			s available upoi through orderi	n request, the device will be assigned a ng codes	

Outline Drawing

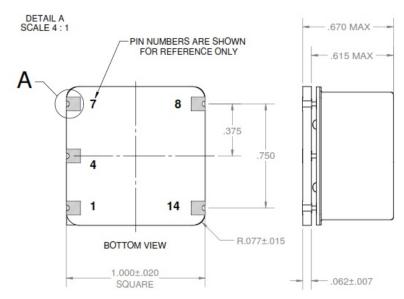
Dimensions in mm



Code	Height "H"	Pin Length "L" Min				
0	15.0	6.2				
Pin Connections						
1	RF Output					
2	Ground (Case)					
3	Electronic Frequency Control Input (EFC)/ No Connect					
4	Reference Voltage					
5	Supply Voltage Input (VS)					

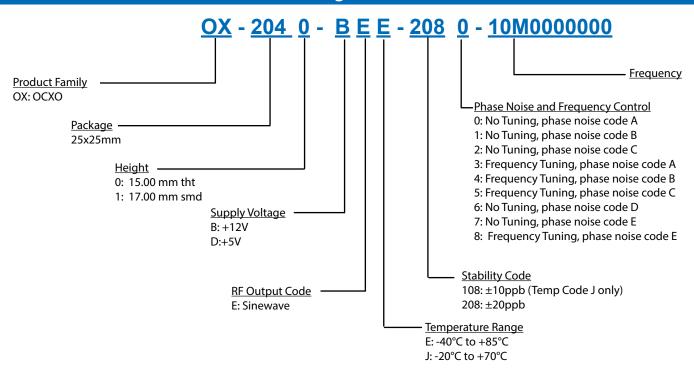


Dimensions in inches



Code	Height "H"	Pin Length "L" Min					
1	17.0 mm	na					
Pin Connections							
1	RF Output						
4	Ground (Case)						
7	Electronic Frequency Control Input (EFC) No Connect for Fixed frequency Oscillators						
8	Reference Voltage						
14	Supply Voltage Input (VS)						

Ordering Information



Notes:

- 1. Contact factory for improved stabilities or additional product options including no pure tin options.
- 2. Certain codes available for sampling and short lead time requests. Please review website for codes.
- 3. Unless otherwise stated, all values are valid after warm-up time and refer to typical conditions for supply voltage, frequency control voltage, load, and temperature (25°C).
- 4. Contact factory for other frequencies. Phase noise degrades for frequencies greater than 10 MHz.
- Subject to technical modification.
- Contact factory for availability.



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Microsemi Headquarters
One Enterprise, Aliso Viejo, CA 92656 USA
Within the USA: +1 (800) 713-4113
Outside the USA: +1 (949) 380-6100
Sales: +1 (949) 380-6136

Fax: +1 (949) 215-4996 email: sales.support@microsemi.com www.microsemi.com Microsemi makes no warranty, representation, or guarantee regarding the information contained herein or the suitability of its products and services for any particular purpose, nor does Microsemi assume any liability whatsoever arising out of the application or use of any product or circuit. The products sold hereunder and any other products sold by Microsemi have been subject to limited testing and should not be used in conjunction with mission-critical equipment or applications. Any performance specifications are believed to be reliable but are not verified, and Buyer must conduct and complete all performance and other testing of the products, alone and together with, or installed in, any end-products. Buyer shall not rely on any data and performance specifications or parameters provided by Microsemii. It is the Buyer's responsibility to independently determine suitability of any products and to test and verify the same. The information provided by Microsemii, and the article representation of the products are considered with such information is entirely with the Buyer. Microsemi does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other IP rights, whether with regard to such information itself or anything described by such information. Information provided in this document is proprietary to Microsemii, and Microsemii reserves the right to make any changes to the information in this document or to products and services at any time without notice.

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